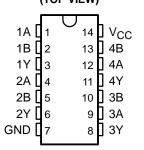
- Operates From 1.65 V to 3.6 V
- Max t<sub>pd</sub> of 2.9 ns at 3.3 V
- ±24-mA Output Drive at 3.3 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

#### description/ordering information

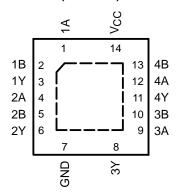
This quadruple 2-input positive-AND gate is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The device performs the Boolean function  $Y = A \bullet B$  or  $Y = \overline{\overline{A} + \overline{B}}$  in positive logic.

## D, DGV, NS, OR PW PACKAGE (TOP VIEW)



# RGY PACKAGE (TOP VIEW)



#### ORDERING INFORMATION

| TA            | PACKAGE <sup>†</sup> |               | ORDERABLE<br>PART NUMBER | TOP-SIDE<br>MARKING |
|---------------|----------------------|---------------|--------------------------|---------------------|
|               | QFN -RGY             | Tape and reel | SN74ALVC08RGYR           | VA08                |
|               | SOIC – D             | Tube          | SN74ALVC08D              | ALVC08              |
| –40°C to 85°C | 30IC - D             | Tape and reel | SN74ALVC08DR             | ALVCOO              |
| -40 C to 65 C | SOP - NS             | Tape and reel | SN74ALVC08NSR            | ALVC08              |
|               | TSSOP – PW           | Tape and reel | SN74ALVC08PWR            | VA08                |
|               | TVSOP – DGV          | Tape and reel | SN74ALVC08DGVR           | VA08                |

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

# FUNCTION TABLE (each gate)

| INP | UTS | OUTPUT |
|-----|-----|--------|
| Α   | В   | Υ      |
| Н   | Н   | Н      |
| L   | X   | L      |
| Х   | L   | L      |



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#### logic diagram, each gate (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage range, V <sub>CC</sub>                              |         |
|--|---------|
| Output voltage range, V <sub>O</sub> (see Notes 1 and 2)           |         |
| Input clamp current, $I_{IK}$ ( $V_I < 0$ )                        |         |
| Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)         |         |
| Continuous output current, IO                                      |         |
| Continuous current through V <sub>CC</sub> or GND                  | ±100 mA |
| Package thermal impedance, θ <sub>JA</sub> (see Note 3): D package |         |
| (see Note 3): DGV package  | 127°C/W |
| (see Note 3): NS package   |         |
| (see Note 3): PW package   | 113°C/W |
| (see Note 4): RGY package  | 47°C/W  |
| Storage temperature range, T <sub>stg</sub>                        |         |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- 2. This value is limited to 4.6 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51-7.
- 4. The package thermal impedance is calculated in accordance with JESD 51-5.



NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### recommended operating conditions (see Note 5)

|                |   |  | MIN                    | MAX                  | UNIT |  |
|----------------|---|--|------------------------|----------------------|------|--|
| Vcc            | Supply voltage                          |  | 1.65                   | 3.6                  | V    |  |
|                |   | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 0.65 × V <sub>CC</sub> |                      |      |  |
| ٧ıH            | High-level input voltage                | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$   | 1.7                    |                      | V    |  |
|                |   | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$   | 2                      |                      |      |  |
|                |   | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ |                        | $0.35 \times V_{CC}$ |      |  |
| $V_{IL}$       | V <sub>IL</sub> Low-level input voltage | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$   |                        | 0.7                  | V    |  |
|                |   | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$   |                        | 0.8                  |      |  |
| VI             | Input voltage                           |  | 0                      | 3.6                  | V    |  |
| ٧o             | Output voltage                          |  | 0                      | VCC                  | V    |  |
|                |   | V <sub>CC</sub> = 1.65 V                     |                        | -4                   |      |  |
| lau            | High lovel output ourront               | V <sub>CC</sub> = 2.3 V                      |                        | -12                  | mA   |  |
| ЮН             | High-level output current               | V <sub>CC</sub> = 2.7 V                      |                        | -12                  |      |  |
|                |   | V <sub>CC</sub> = 3 V                        |                        | -24                  |      |  |
|                |   | V <sub>CC</sub> = 1.65 V                     |                        | 4                    |      |  |
| 1              | Low lovel output ourrent                | V <sub>CC</sub> = 2.3 V                      |                        | 12                   |      |  |
| lOL            | Low-level output current                | V <sub>CC</sub> = 2.7 V                      |                        | 12                   | mA   |  |
|                |   | V <sub>CC</sub> = 3 V                        |                        | 24                   |      |  |
| Δt/Δν          | Input transition rise or fall rate      |  |                        | 5                    | ns/V |  |
| T <sub>A</sub> | Operating free-air temperature          |  | -40                    | 85                   | °C   |  |

NOTE 5: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER      | TEST CON                              | NDITIONS                               | VCC             | MIN                 | TYP† | MAX  | UNIT |
|----------------|---------------------------------------|--|-----------------|---------------------|------|------|------|
|                | $I_{OH} = -100 \mu\text{A}$           |  | 1.65 V to 3.6 V | V <sub>CC</sub> -0. | 2    |      |      |
|                | $I_{OH} = -4 \text{ mA}$              |  | 1.65 V          | 1.2                 |      |      |      |
|                | $I_{OH} = -6 \text{ mA}$              |  | 2.3 V           | 2                   |      |      |      |
| Voн            |                                       |  | 2.3 V           | 1.7                 |      |      | V    |
|                | $I_{OH} = -12 \text{ mA}$             |  | 2.7 V           | 2.2                 |      |      |      |
|                |                                       | 3 V                                    | 2.4             |                     |      |      |      |
|                | $I_{OH} = -24 \text{ mA}$             |  | 3 V             | 2                   |      |      |      |
|                | I <sub>OL</sub> = 100 μA              |  | 1.65 V to 3.6 V |                     |      | 0.2  |      |
|                | $I_{OL} = 4 \text{ mA}$               |  | 1.65 V          |                     |      | 0.45 |      |
| Voi            | $I_{OL} = 6 \text{ mA}$               |  | 2.3 V           |                     |      | 0.4  | V    |
| VOL            | lo. – 12 mA                           | 2.3 V                                  |                 |                     | 0.7  | ď    |      |
|                | I <sub>OL</sub> = 12 mA               |  | 2.7 V           |                     |      | 0.4  |      |
|                | $I_{OL} = 24 \text{ mA}$              |  | 3 V             |                     |      | 0.55 |      |
| lį             | $V_I = V_{CC}$ or GND                 |  | 3.6 V           |                     |      | ±5   | μΑ   |
| Icc            | $V_I = V_{CC}$ or GND,                | IO = 0                                 | 3.6 V           |                     |      | 10   | μΑ   |
| ∆lcc           | One input at V <sub>CC</sub> – 0.6 V, | Other inputs at V <sub>CC</sub> or GND | 3 V to 3.6 V    |                     |      | 750  | μΑ   |
| C <sub>i</sub> | $V_I = V_{CC}$ or GND                 |  | 3.3 V           |                     | 4.5  | ·    | pF   |

<sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .



### SN74ALVC08 QUADRUPLE 2-INPUT POSITIVE-AND GATE

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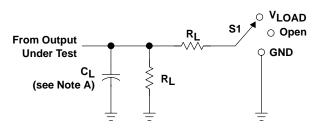
# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

| PARAMETER       | FROM<br>(INPUT) (OL | TO<br>(OUTPUT) | V <sub>CC</sub> = 1.8 V<br>± 0.15 V |     | V <sub>CC</sub> = 2.5 V<br>± 0.2 V |     | V <sub>CC</sub> = 2.7 V |     | V <sub>CC</sub> = 3.3 V<br>± 0.3 V |     | UNIT |
|-----------------|---------------------|----------------|-------------------------------------|-----|------------------------------------|-----|-------------------------|-----|------------------------------------|-----|------|
|                 |                     | (0011 01)      | MIN                                 | MAX | MIN                                | MAX | MIN                     | MAX | MIN                                | MAX |      |
| t <sub>pd</sub> | A or B              | Y              | 1.2                                 | 5.3 | 1                                  | 3.2 |                         | 3   | 1.2                                | 2.9 | ns   |

## operating characteristics, $T_A = 25^{\circ}C$

| PARAMETER |                 | TEST CONDITIONS                        |                     | V <sub>CC</sub> = 1.8 V V <sub>CC</sub> = 2.5 V V <sub>CC</sub> = 3. |     | $V_{CC} = 3.3 \text{ V}$ | UNIT |      |  |
|-----------|-----------------|--|---------------------|--|-----|--------------------------|------|------|--|
|           | PARAMETER       |  | TEST CONDITIONS     |  | TYP | TYP                      | TYP  | ONII |  |
| I         | C <sub>pd</sub> | Power dissipation capacitance per gate | C <sub>L</sub> = 0, | f = 10 MHz   | 24  | 25                       | 26   | pF   |  |

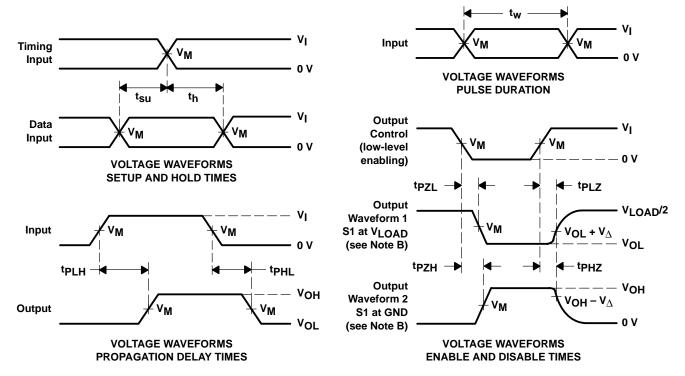
#### PARAMETER MEASUREMENT INFORMATION



| TEST            | S1                |
|-----------------|-------------------|
| <sup>t</sup> pd | Open              |
| tPLZ/tPZL       | V <sub>LOAD</sub> |
| tPHZ/tPZH       | GND               |

**LOAD CIRCUIT** 

| V                 | IN             | INPUT                          |                    | V                 | C     | D.           | V                              |
|-------------------|----------------|--------------------------------|--------------------|-------------------|-------|--------------|--------------------------------|
| vcc               | ٧ <sub>I</sub> | t <sub>r</sub> /t <sub>f</sub> | VМ                 | VLOAD             | CL    | RL           | $v_{\scriptscriptstyle\Delta}$ |
| 1.8 V ± 0.15 V    | VCC            | ≤2 ns                          | V <sub>CC</sub> /2 | 2×V <sub>CC</sub> | 30 pF | <b>1 k</b> Ω | 0.15 V                         |
| 2.5 $\pm$ 0.2 V   | VCC            | ≤2 ns                          | V <sub>CC</sub> /2 | 2×V <sub>CC</sub> | 30 pF | <b>500</b> Ω | 0.15 V                         |
| 2.7 V             | 2.7 V          | ≤2.5 ns                        | 1.5 V              | 6 V               | 50 pF | 500 Ω        | 0.3 V                          |
| 3.3 V $\pm$ 0.3 V | 2.7 V          | ≤2.5 ns                        | 1.5 V              | 6 V               | 50 pF | 500 Ω        | 0.3 V                          |



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ .
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzi and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



#### DGV (R-PDSO-G\*\*)

#### 24 PINS SHOWN

#### **PLASTIC SMALL-OUTLINE**

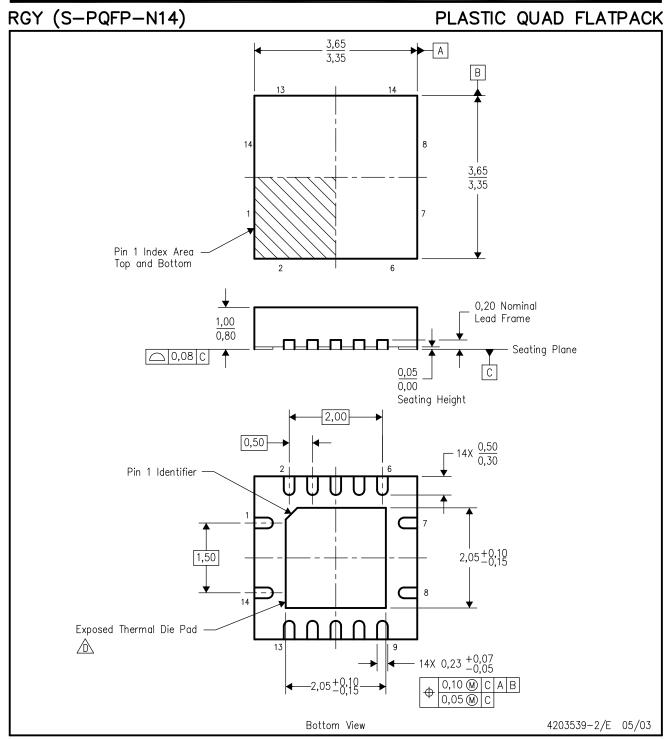


NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



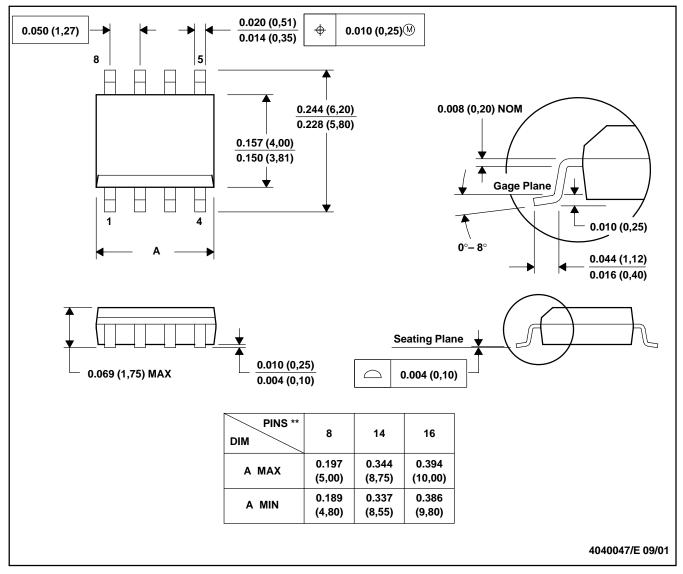
- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. QFN (Quad Flatpack No-Lead) package configuration.
  - The package thermal performance may be enhanced by bonding the thermal die pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected ground leads.
  - E. Package complies to JEDEC MO-241 variation BA.



#### D (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

#### **8 PINS SHOWN**



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

#### **MECHANICAL DATA**

### NS (R-PDSO-G\*\*)

## 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

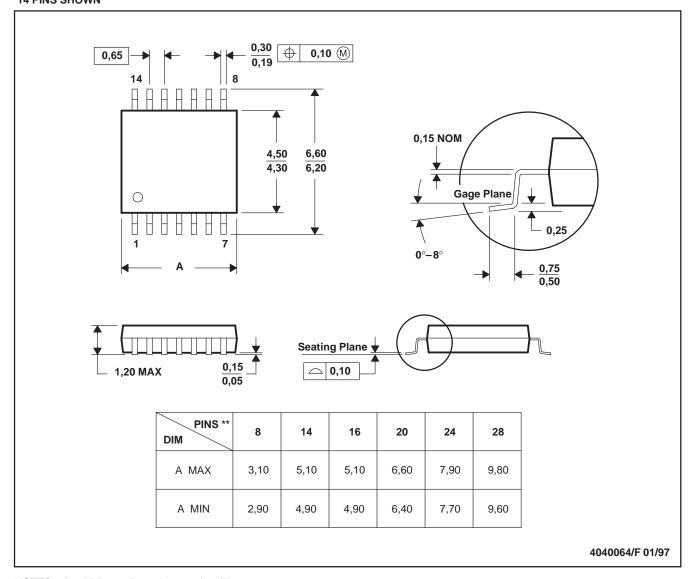
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



#### PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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